

# MPSA20 **NPN General Purpose Amplifier**

## Features

- BVceo .....40V(Min)
- hFE ..... 40~400 @ Vce=10V, Ic=5mA
- Pb free
- Sourced from process 10



1. Emitter 2. Base 3. Collector

## Absolute Maximum Ratings $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Unit
V <sub>CEO</sub>	Collector-Emitter Voltage	40	V
V <sub>EBO</sub>	Emitter-Base Voltage	4	V
I <sub>C</sub>	Collector Current	100	mA
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature Range	-55 ~ 150	°C

1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

## Thermal Characteristics\* Ta=25°C unless otherwise noted

Symbol	Parameter	Мах	Unit
P <sub>C</sub>	Collector Power Dissipation, by $R_{\theta JA}$	625	mW
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	200	°C/W

These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.
These ratings are based on a maximum junction temperature of 150 degrees C.
Device mounted on FR-4 PCB 36mm \* 1.5mm: Mounting pad for the collector lead min.6cm.

### Electrical Characteristics\* Ta=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Unit
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 1 {\rm mA},  I_{\rm B} = 0$	40		V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_{\rm E} = 100 \mu A, I_{\rm C} = 0$	4		V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = 30V		100	nA
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 10V, I_{C} = 5mA$	40	400	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 1 {\rm mA}$		0.25	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE} = -10V, I_{C} = -10mA$	-0.5	-1.2	V
C <sub>cb</sub>	Output Capacitance	$V_{CB} = 10V, f = 100kHz$		4.0	pF
f <sub>T</sub>	Current Gain Bandwithd Product	$V_{CE}$ = 10V, $I_{C}$ = 5mA, f = 100MHz	125		Mhz

\* DC Item are tested by Pulse Test : Pulse Width≤300us, Duty Cycle≤2%

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